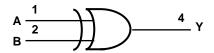


# **Pin Descriptions**

Pin Name	Pin NO.	Description		
Α	1	Data Input		
В	2	Data Input		
GND	3	Ground		
Y	4	Data Output		
V <sub>CC</sub>	5	Supply Voltage		

# **Logic Diagram**



# **Function Table**

Inpi	Output	
Α	В	Υ
Н	Н	L
L	Н	Н
Н	L	Н
L	L	L



## **Absolute Maximum Ratings (Note 2)**

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
$V_{CC}$	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> <0	-20	mA
lok	Output Clamp Current (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20	mA
Io	Continuous output current (V <sub>O</sub> = 0 to V <sub>CC</sub> )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

# **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit
V <sub>CC</sub>	Operating Voltage		2	5.5	V
		$V_{CC} = 2V$	1.5		
$V_{IH}$	High-level Input Voltage	$V_{CC} = 3V$	2.1		V
		$V_{CC} = 5.5V$	3.85		
		V <sub>CC</sub> = 2V		0.5	
$V_{IL}$	Low-level input voltage	$V_{CC} = 3V$		0.9	V
		$V_{CC} = 5.5V$		1.65	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 2V		-50	uA
I <sub>OH</sub>	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{V}$		-4	A
		$V_{CC} = 5V \pm 0.5V$		-8	- mA
		V <sub>CC</sub> = 2V		50	uA
I <sub>OL</sub>	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4	^
		$V_{CC} = 3V$		8	mA mA
A+/A>/	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	A /
Δt/ΔV	rate	$V_{CC} = 5V \pm 0.5V$		20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at  $V_{\text{CC}}$  or Ground.



### **Electrical Characteristics**

0	D	Table Camalitians	V		25ºC		-40°C 1	to 85°C	-40°C to	o 125ºC	1.1		
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Min	Max	Min	Max	Unit		
		I <sub>OH</sub> = -50μA			2V	1.9	2		1.9		1.9		
	High Level		3V	2.9	3		2.9		2.9				
V <sub>OH</sub>	Output		4.5V	4.4	4.5		4.4		4.4		V		
	Voltage	$I_{OH} = -4mA$	3V	2.58			2.48		2.40				
		$I_{OH} = -8mA$	4.5V	3.94			3.8		3.70				
			2V			0.1		0.1		0.1			
	Low Level	$I_{OL} = 50\mu A$	3V			0.1		0.1		0.1			
$V_{OL}$	Output		4.5V			0.1		0.1		0.1	V		
	Voltage	$I_{OL} = 4mA$	3V			0.36		0.44		0.55			
		$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55			
l <sub>l</sub>	Input Current	V <sub>I</sub> = 5.5 V or GND	0 to 5.5V			± 0.1		± 1		± 2	μΑ		
Icc	Supply Current	$V_I = 5.5V$ or GND $I_O=0$	5.5V			1		10		40	μΑ		
C <sub>i</sub>	Input Capacitance	$V_I = V_{CC} - \text{or GND}$	5.5V		2.0	10		10		10	pF		
$\theta_{JA}$	Thermal Resistance	SOT25	(Note 4)		195						°C/W		
ОЈД	Junction-to- Ambient	SOT353	(11018 4)		430						0/ **		
	Thermal Resistance	SOT25			58								
θ <sub>JC</sub>	Junction-to- Case	SOT353	(Note 4)		155						°C/W		

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

# **Switching Characteristics**

#### $V_{CC} = 3.3V \pm 0.3$ (see Figure 1)

Doromotor	From	ТО			25°C		-40°C t	o 85ºC	-40°C to	o 125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
4	A or B	V	C <sub>L</sub> =15pF	0.6	4.0	11.0	0.6	13.0	0.6	14.0	ns
t <sub>pd</sub>	AOIB	r	C <sub>L</sub> =50pF	0.6	5.8	14.5	0.6	16.5	0.6	18.5	ns

#### $V_{CC} = 5V \pm 0.5V$ (see Figure 1)

Parameter	From	ТО			25ºC		-40°C t	o 85ºC	-40°C to	125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Onit
	A or B	V	C <sub>L</sub> =15pF	0.6	3.4	6.8	0.6	8.0	0.6	8.5	ns
t <sub>pd</sub>	AOIB	Ť	C <sub>L</sub> =50pF	0.6	4.9	8.8	0.6	10.0	0.6	11.5	ns

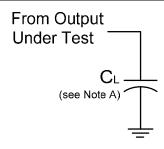


# **Operating Characteristics**

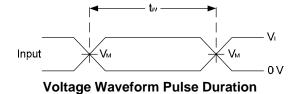
 $T_A = 25 \, {}^{\circ}C$ 

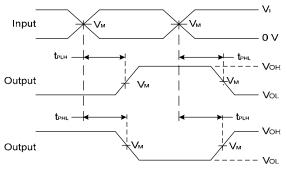
Parameter		Test Conditions	V <sub>CC</sub> = 5 V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz No Load	12	pF

### **Parameter Measurement Information**



V	In	puts	V	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

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# **Ordering Information**

T4AHC1G 86 XX - 7

Logic Device Function Package Packing

74 : Logic Prefix 86 : 2-Input W5 : SOT25 7 : Tape & Reel

SE: SOT353

AHC: 2 to 5.5V Family

Family 1G : One gate

	Davisa	Package	Packaging	7" Tape	and Reel
	Device	Code	(Note 5)	Quantity	Part Number Suffix
<b>Pb</b> ,	74AHC1G86W5-7	W5	SOT25	3000/Tape & Reel	-7
Pb,	74AHC1G86SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

XOR-Gate

## **Marking Information**

#### (Top View)

<u>XX Y W X</u>

<u>W</u>: Week: A~Z: 1~26 week;
a~z: 27~52 week; z represents
52 and 53 week

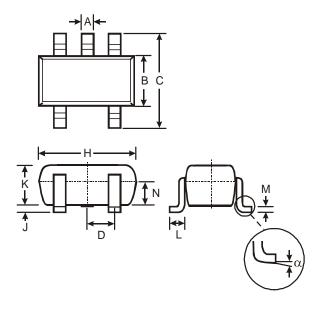
2 3 <u>X</u>: A~Z: Internal code

Part Number	Package	Identification Code
74AHC1G86W5	SOT25	YX
74AHC1G86SE	SOT353	YX



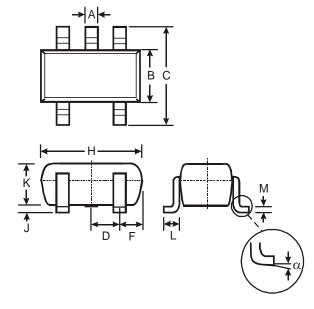
# Package Outline Dimensions (All Dimensions in mm)

### (1) Package Type: SOT25



SOT25								
Dim	Dim Min Max Typ							
A	0.35	0.50	0.38					
В	1.50	1.70	1.60					
O	2.70	3.00	2.80					
D	_	_	0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
K	1.00	1.30	1.10					
L	0.35	0.55	0.40					
M	0.10	0.20	0.15					
Ν	0.70	0.80	0.75					
α	0°	8°	_					
AII D	imens	ions i	n mm					

### (2) Package Type: SOT353



SOT353		
Dim	Min	Max
Α	0.10	0.30
В	1.15	1.35
С	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
Н	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
М	0.10	0.22
α	0°	8°
All Dimensions in mm		



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